

SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2564
(F8F60VX2)**

600V 8A

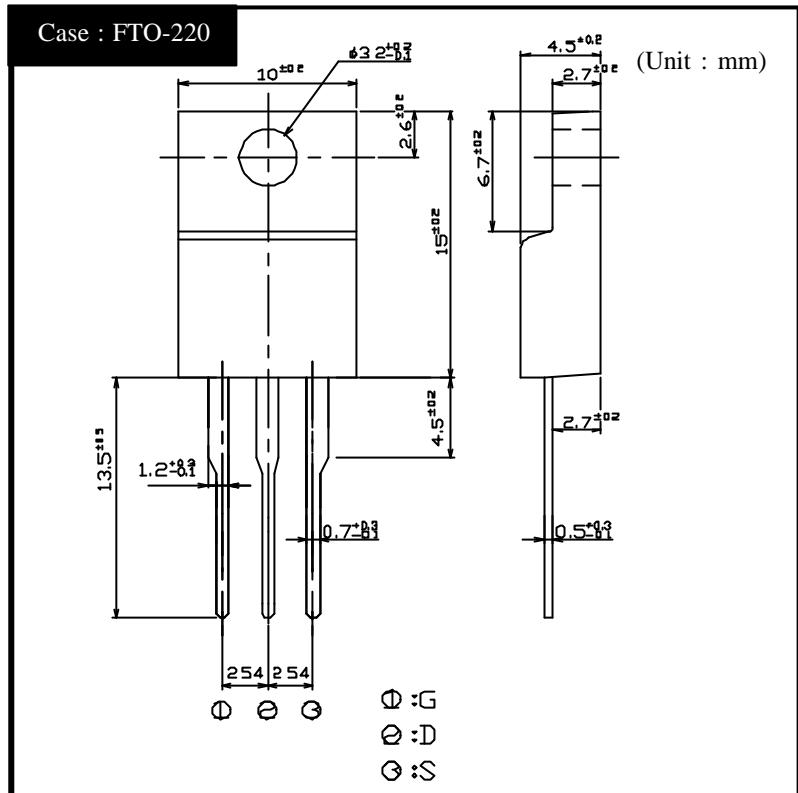
FEATURES

Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
The static $R_{ds(on)}$ is small.
The switching time is fast.
Avalanche resistance guaranteed.

APPLICATION

Switching power supply of AC 100-200V input
Inverter
Power Factor Control Circuit

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings (T_c = 25 °C)

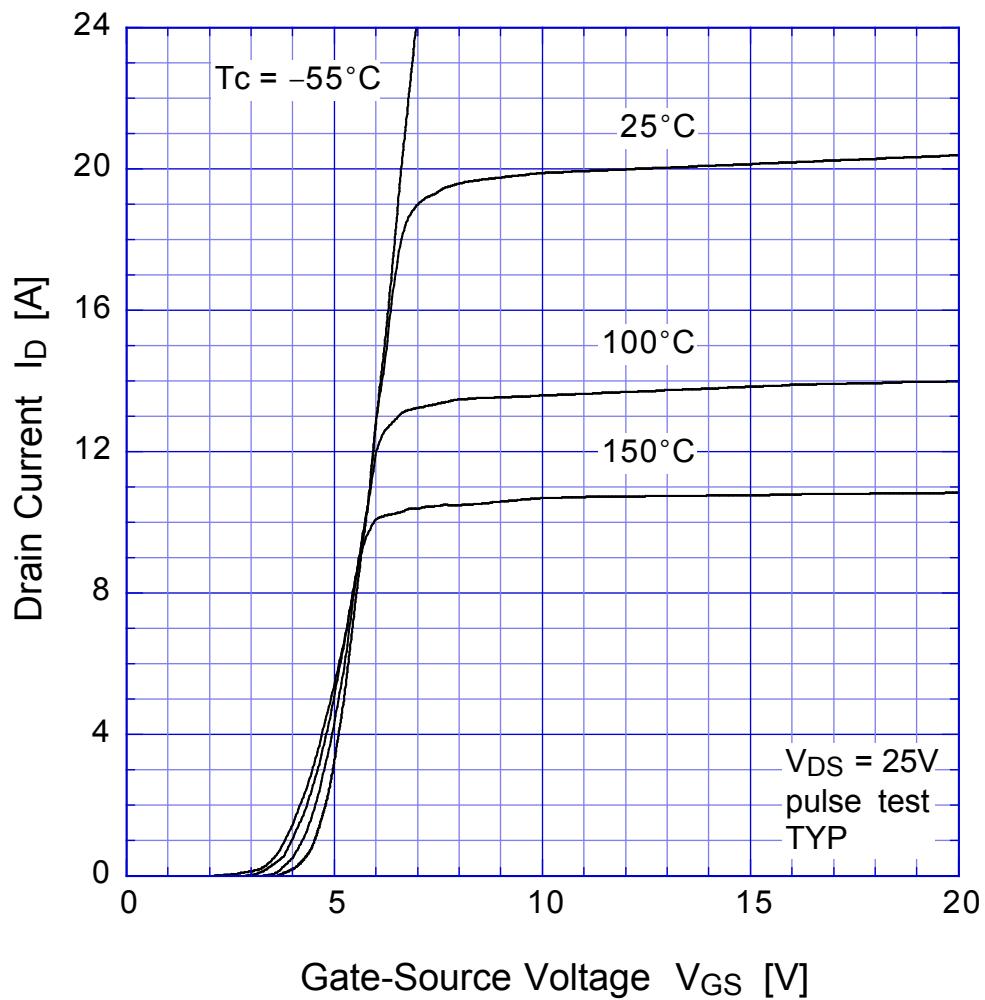
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55 ~ 150	
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		600	V
Gate-Source Voltage	V _{GSS}		± 30	
Continuous Drain Current (DC)	I _D		8	
Continuous Drain Current (Peak)	I _{DP}		24	A
Continuous Source Current (DC)	I _S		8	
Total Power Dissipation	P _T		50	W
Single Pulse Avalanche Current	I _{AS}	T _{ch} = 25	8	A
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	T _{OR}	(Recommended torque : 0.3N·m)	0.5	N·m

●Electrical Characteristics T_c = 25°C

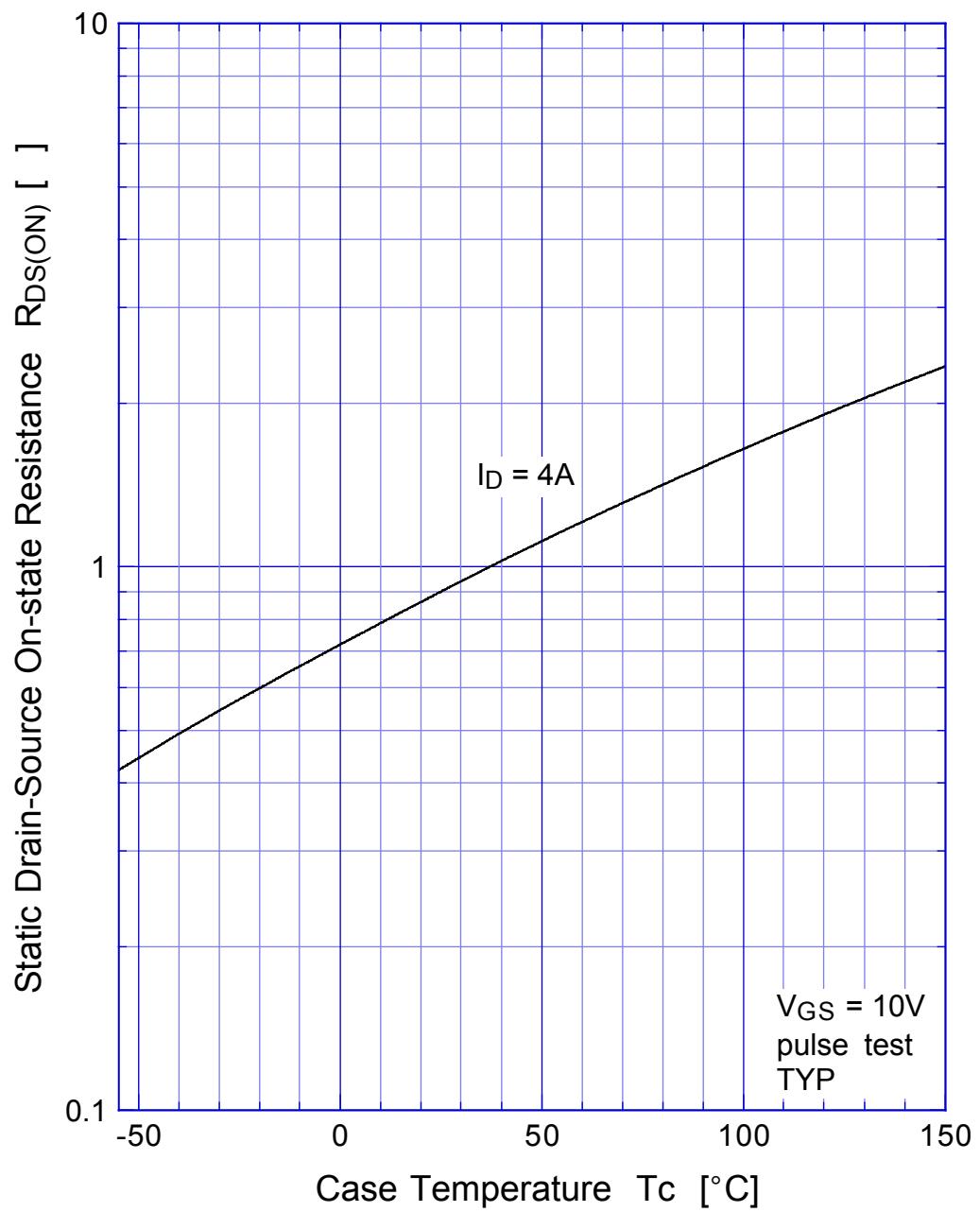
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, VGS = 0V	600			V
Zero Gate Voltage Drain Current	I _{DSS}	VDS = 600V, VGS = 0V			250	μA
Gate-Source Leakage Current	I _{GSS}	VGS = ±30V, VDS = 0V			±0.1	
Forward Transconductance	g _{fS}	ID = 4A, VDS = 10V	2.4	5.5		S
Static Drain-Source On-state Resistance	R _{D(S)ON}	ID = 4A, VGS = 10V		0.9	1.2	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, VDS = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forwade Voltage	V _{SD}	IS = 4A, VGS = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			2.5	°C/W
Total Gate Charge	Q _g	VDD = 400V, VGS = 10V, ID = 8A		42		nC
Input Capacitance	C _{iss}	VDS = 10V, VGS = 0V, f = 1MHz	1130			pF
Reverse Transfer Capacitance	C _{rss}			85		
Output Capacitance	C _{oss}			245		
Turn-On Time	t _{on}	ID = 4A, RL = 37.5Ω, VGS = 10V	55	80	ns	
Turn-Off Time	t _{off}			195	290	

2SK2564

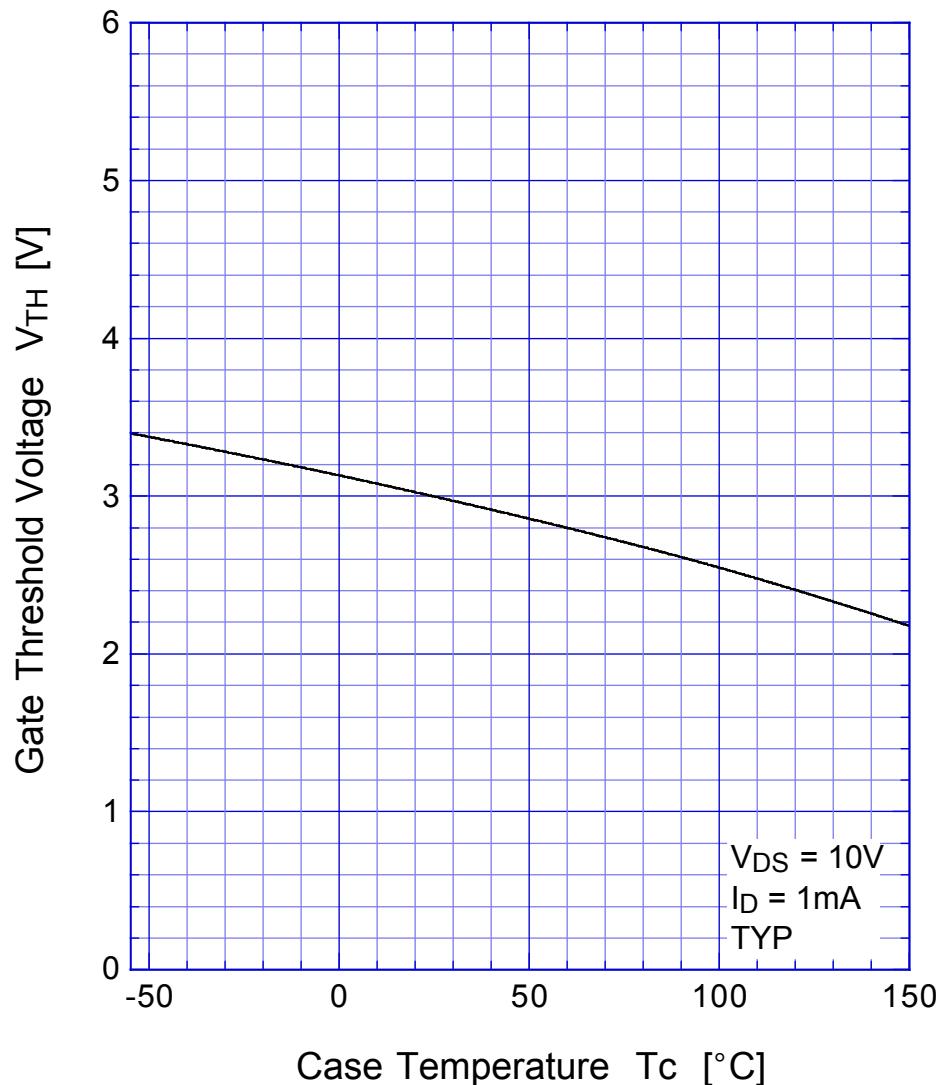
Transfer Characteristics



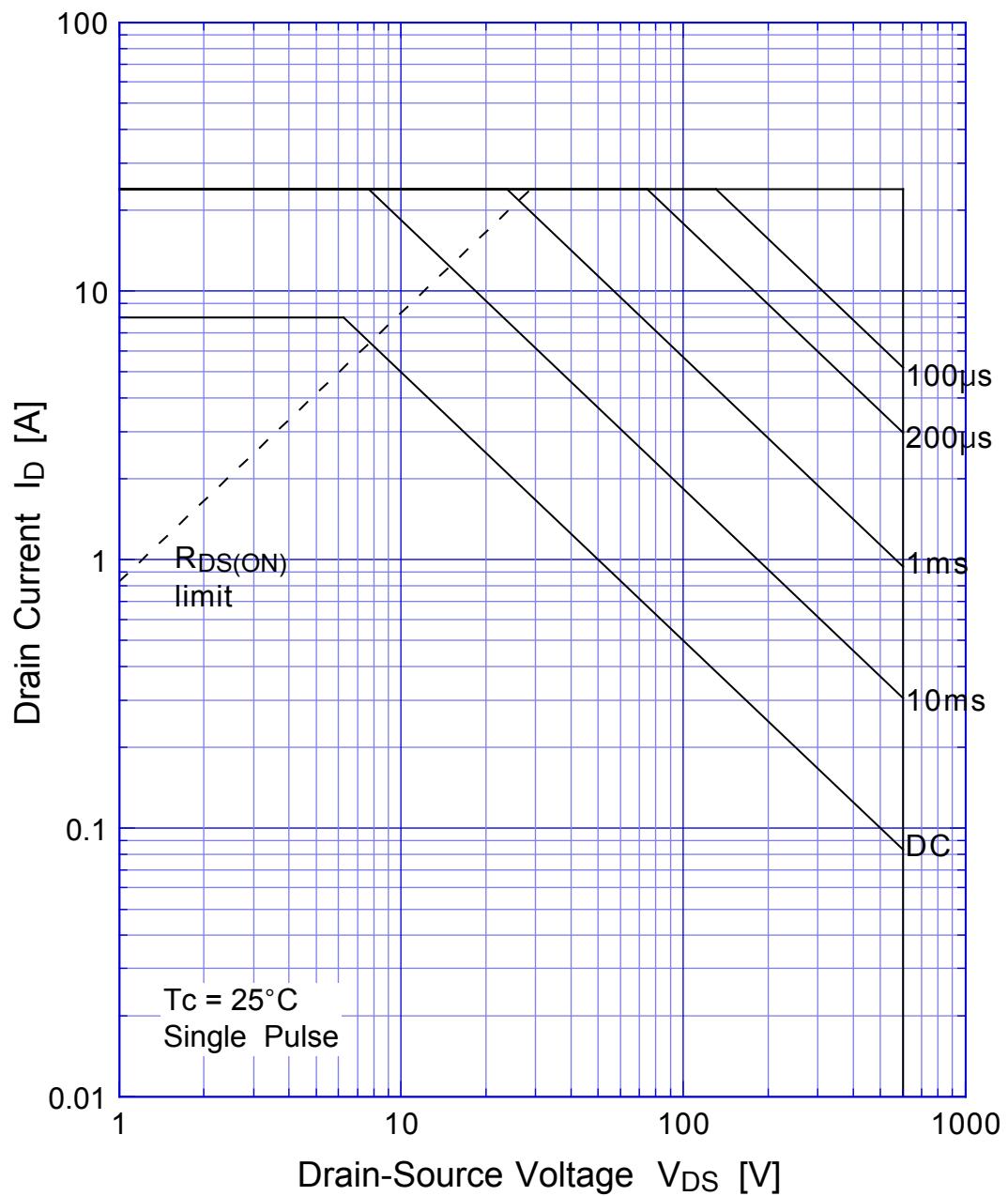
2SK2564 Static Drain-Source On-state Resistance



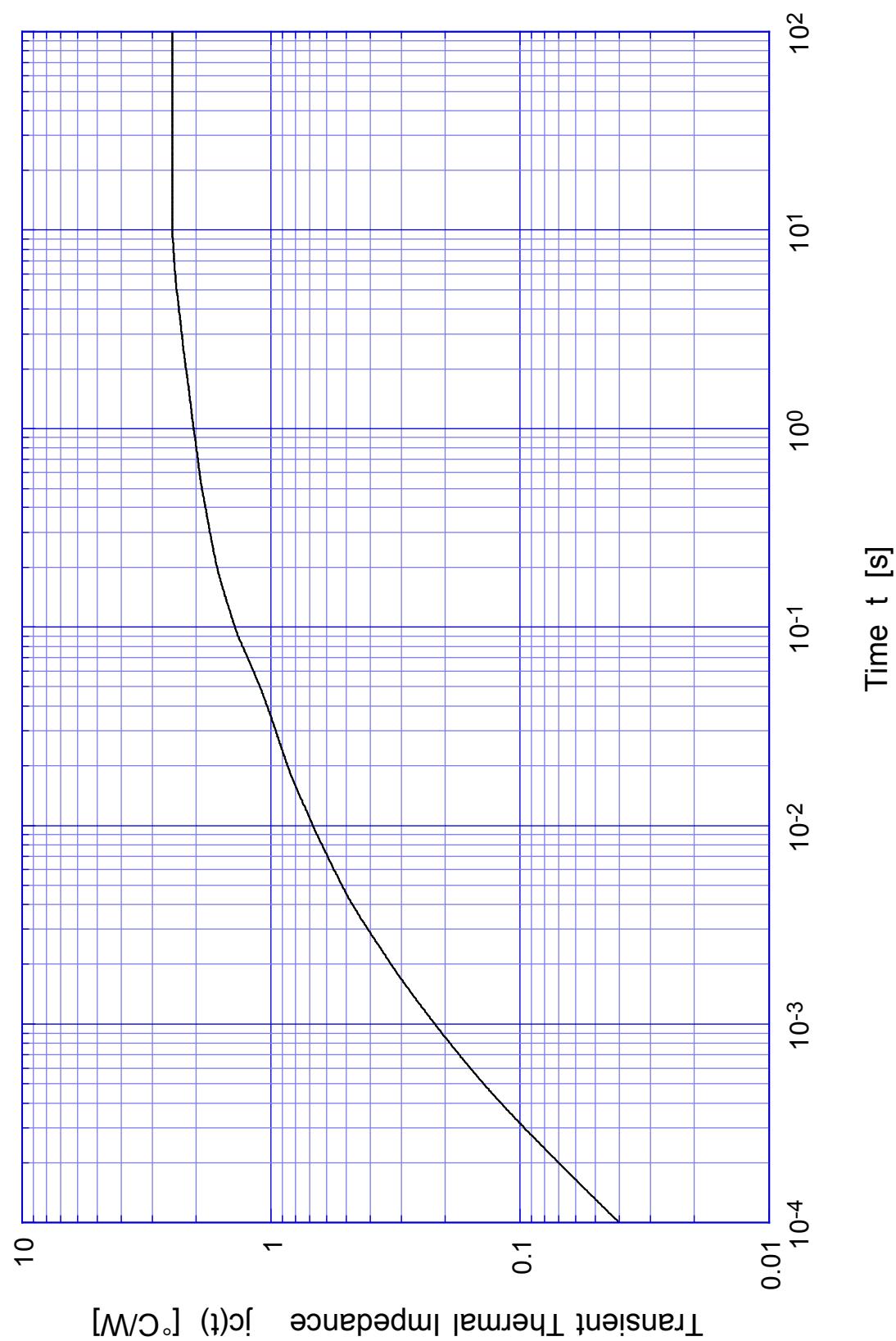
2SK2564 Gate Threshold Voltage



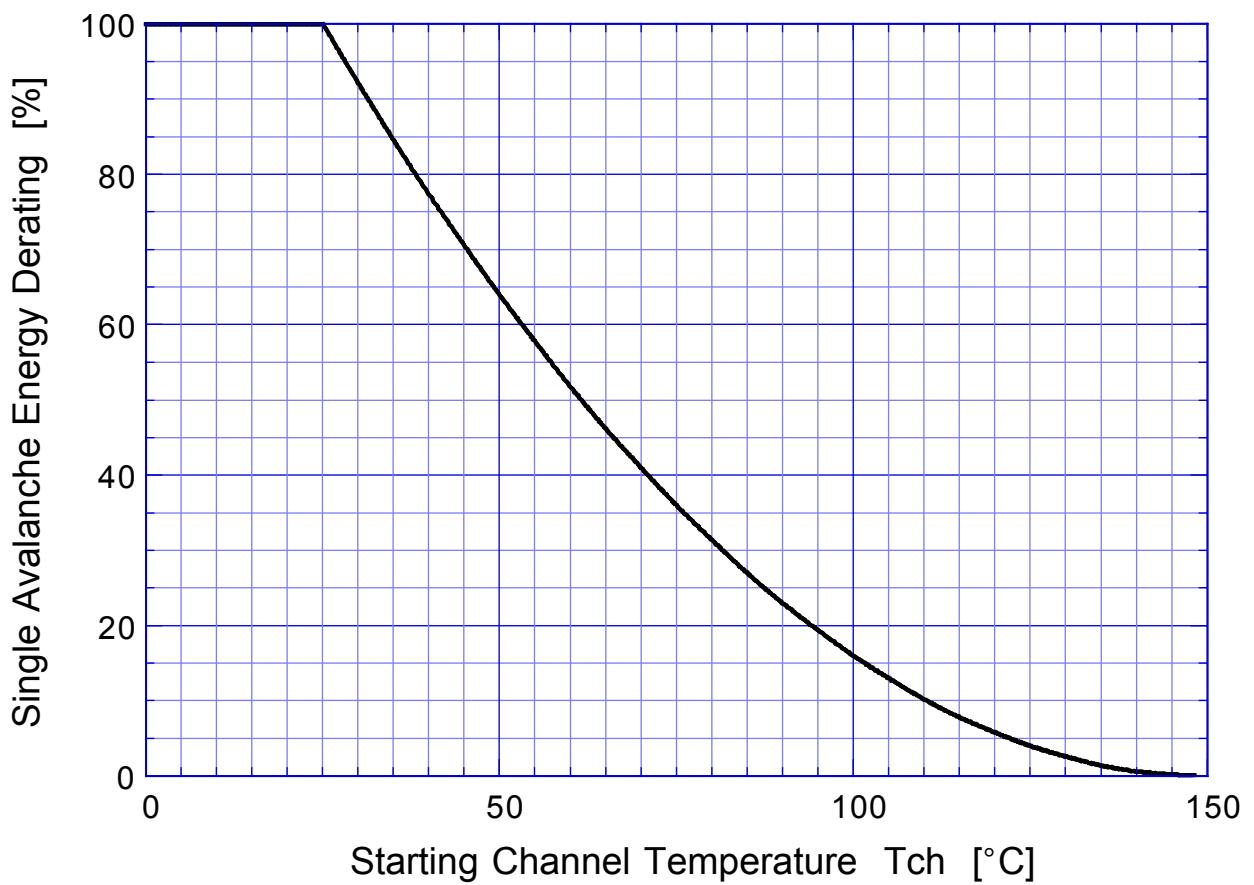
2SK2564 Safe Operating Area



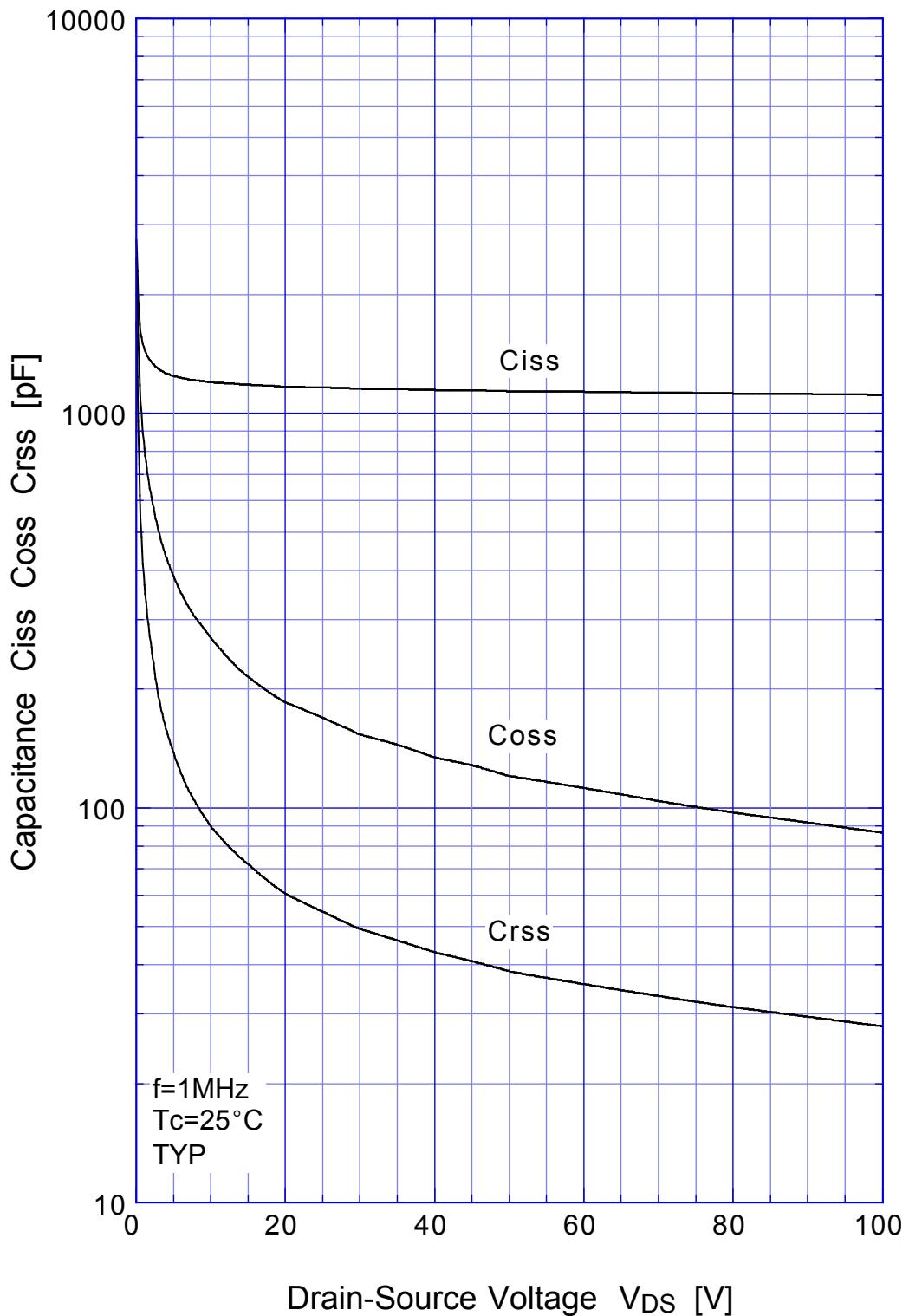
2SK2564 Transient Thermal Impedance



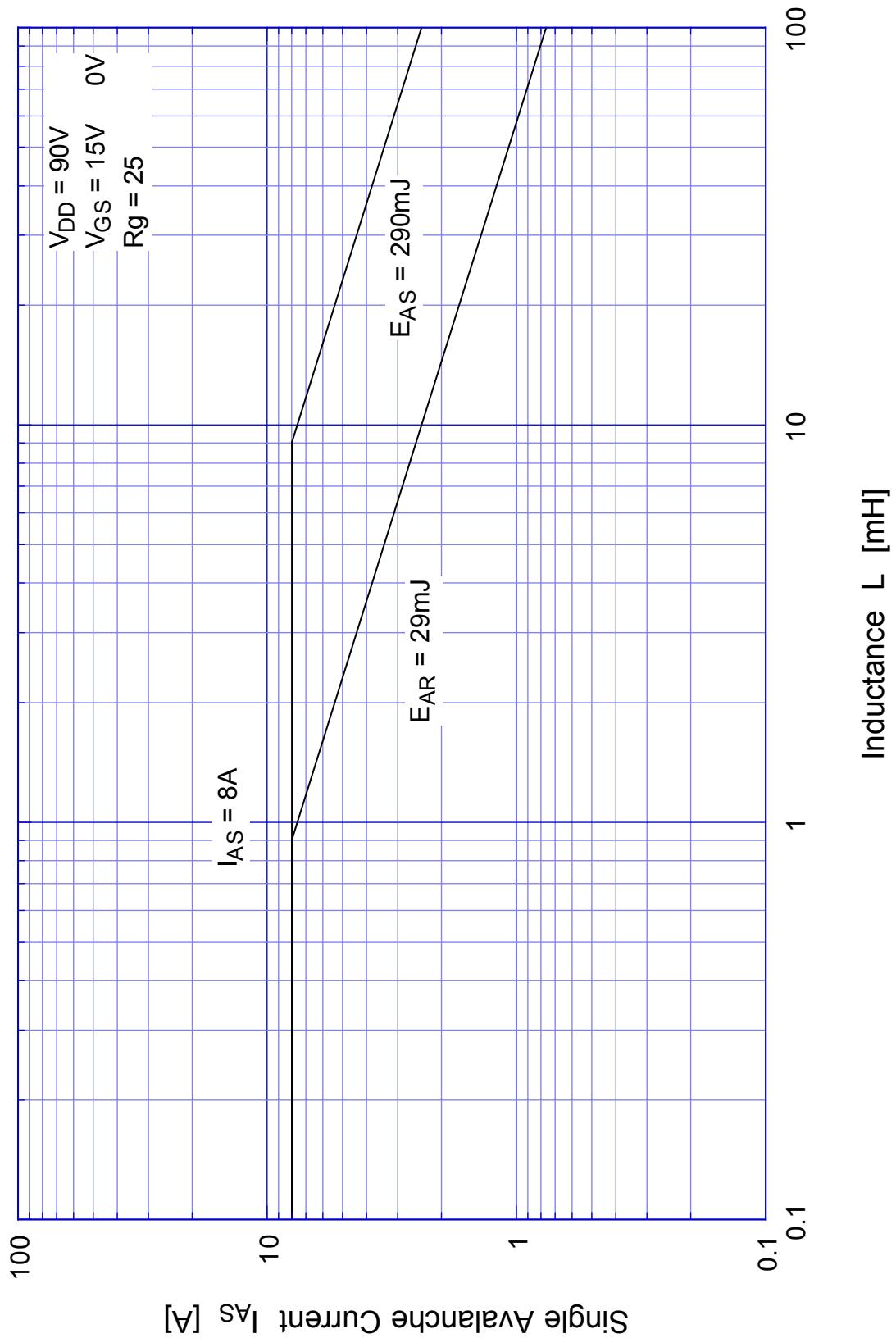
2SK2564 Single Avalanche Energy Derating



2SK2564 Capacitance

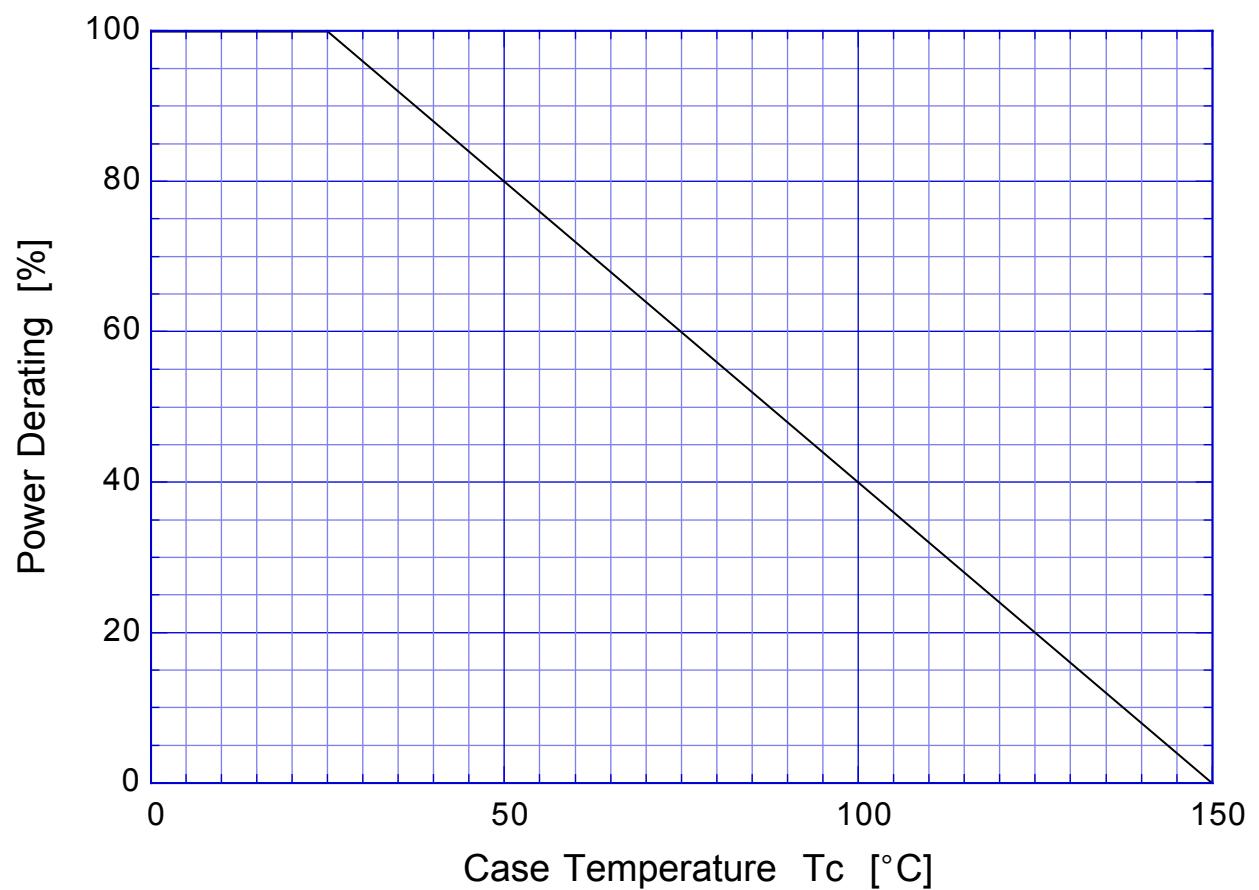


2SK2564 Single Avalanche Current - Inductive Load



2SK2564

Power Derating



2SK2564

Gate Charge Characteristics

